



M T B F

(E I A J R C R - 9 1 0 2)

Model	DAS100F24
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Reference
1	I C	Monolithic	3	0.0890	
2		Hybrid	0	0.0000	
3	Transistors		11	0.2488	
4	Diodes		25	0.4750	
5	LED·Optocouplers		2	0.1400	
6	Resistors		91	0.9572	
7	Capacitors		42	0.3786	
8	Transformer·Choke Coil		7	0.3750	
9	Connectors		425	0.0584	
10	Others		3	0.1160	
Total Failure Rate [10 ⁻⁶ /H]				2.8380	

M T B F	[H]	353,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—